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Substitute for Form 1449/PTO		<i>Complete if Known</i>	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		Application Number	10/529673
		Filing Date	11/22/2004
		First Named Inventor	Dominik EISERT
		Art Unit	2823
		Examiner Name	William M. Brewster
Sheet	1	of	2
		Attorney Docket Number	5367-167PUS

U.S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ² Number ³ Kind-Code ⁴ (if known)				
WB	X	EP 0 184 117 A	06/11/1986	Siemens AG		
WA	X	DE 199 05 517 A	12/09/1999	Hewlett Packard Co.		
WB	X	WO 01/61766 A	08/23/2001	Yanagihara et al.		
WB	X	DE 100 40 448 A	03/07/2002	Osram Opto Semiconductors GmbH		
WB	X	WO 01/41225 A	06/07/2001	Cree Lighting Co.		

Examiner Signature	William M. Brewster	Date Considered	25 JAN 87
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Substitute for Form 1449/PTO		<i>Complete if Known</i>	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		10/529673	
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		Application Number	
		Filing Date	11/22/2005
		First Named Inventor	Dominik EISERT
		Art Unit	2923
		Examiner Name	W. Liam M. Brewster
		Attorney Docket Number	5367-167PUS

NON-PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T
W/B		Naoki Wada et al., "Stable Operation of AlGaAs/GaAs Light-Emitting Diodes Fabricated on Si Substrate" Japanese Journal of Applied Physics, Vol. 31, Nr. 2A Part 2, pp. L78-L81, February 1, 1992	
W/B		Wada N. et al., "GaAs/AlGaAs Light Emitters Fabricated on Undercut GaAs on Si", Japanese Journal of Applied Physics, Vol. 33, Nr. 3A, pp.	
W/B		1268-1274, March 1, 1994	
W/B		Olsen et al., "Calculated stresses in multilayered heteroepitaxial	
W/B		structures", Journal of Applied Physics, Vol. 48, Nr. 6, pp. 2543-2547	

Examiner Signature	William M. Brewster	Date Considered	28 JAN 87
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